



#### 40V 175°C DUAL N-CHANNEL ENHANCEMENT MODE MOSFET

### **Product Summary**

BV <sub>DSS</sub>	Rds(on) max	I <sub>D</sub> T <sub>A</sub> = +25°C	
40V	$24m\Omega @V_{GS} = 10V$	7.5A	
400	$32m\Omega @V_{GS} = 4.5V$	6.5A	

### **Description**

This new generation MOSFET is designed to minimize the on-state resistance (R<sub>DS(ON)</sub>) and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

## **Applications**

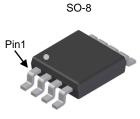
- Motor Control
- Backlighting
- Power Management Functions
- DC-DC Converters

#### **Features**

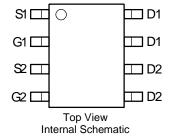
- Rated to +175°C Ideal for High Ambient Temperature Environments
- 100% Unclamped Inductive Switching Ensures More Reliable and Robust End Application
- Low On-Resistance
- Low Input Capacitance
- Fast Switching Speed
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- An Automotive-Compliant Part is Available Under Separate Datasheet (<u>DMNH4026SSDQ</u>)

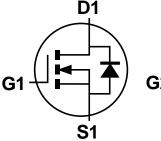
#### **Mechanical Data**

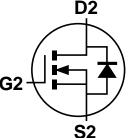
- Case: SO-8
- Case Material: Molded Plastic, "Green" Molding Compound.
  UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections Indicator: See Diagram Below
- Terminals: Finish Matte Tin Annealed over Copper Lead Frame. Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.074 grams (Approximate)



Top View







**Equivalent Circuit** 

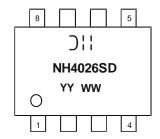
### Ordering Information (Note 4)

I	Part Number	Case	Packaging	
	DMNH4026SSD-13	SO-8	2,500/Tape & Reel	

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

## **Marking Information**



⊃¦¦ = Manufacturer's MarkingNH4026SD = Product Type Marking CodeYYWW = Date Code MarkingYY = Year (ex: 16 = 2016)WW = Week (01 to 53)



# **Maximum Ratings** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Drain-Source Voltage		V <sub>DSS</sub>	40	V
Gate-Source Voltage		$V_{GSS}$	±20	V
Continuous Drain Current (Note 6) V <sub>GS</sub> = 10V	I <sub>D</sub>	7.5 5.3	А	
Maximum Continuous Body Diode Forward Curre	ent (Note 6)	I <sub>S</sub>	2.5	A
Pulsed Drain Current (10µs Pulse, Duty Cycle =	I <sub>DM</sub>	60	A	
Avalanche Current (Note 7) L = 0.1mH		I <sub>AS</sub>	18	A
Avalanche Energy (Note 7) L = 0.1mH		Eas	18	mJ

### **Thermal Characteristics**

Characteristic		Symbol	Value	Unit	
Total Power Dissipation (Note 5)	T <sub>A</sub> = +25°C	P <sub>D</sub>	1.5	W	
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	Б	101	°C/W	
Thermal Resistance, Junction to Ambient (Note 5)	t<10s	$R_{\theta JA}$	59	C/VV	
Total Power Dissipation (Note 6)	T <sub>A</sub> = +25°C	$P_D$	2.0	W	
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	D	74	°C/W	
Thermal Resistance, Junction to Ambient (Note 6)	t<10s	$R_{\theta JA}$	43		
Thermal Resistance, Junction to Case (Note 6)	$R_{ heta JC}$	10.5			
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-55 to +175	°C		

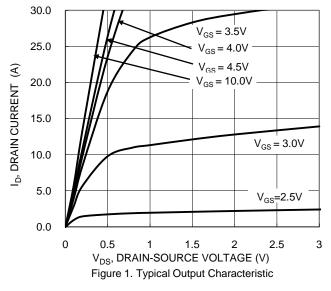
# **Electrical Characteristics** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 8)						
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	40	_	_	V	$V_{GS} = 0V, I_D = 250\mu A$
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	_	_	1	μA	$V_{DS} = 40V, V_{GS} = 0V$
Gate-Source Leakage	I <sub>GSS</sub>	_	_	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$
ON CHARACTERISTICS (Note 8)						
Gate Threshold Voltage	V <sub>GS(TH)</sub>	1	_	3	V	$V_{DS} = V_{GS}$ , $I_D = 250\mu A$
Static Drain-Source On-Resistance	В	_	15	24	mΩ	V <sub>GS</sub> = 10V, I <sub>D</sub> = 6A
Static Dialii-Source Off-Resistance	R <sub>DS(ON)</sub>	_	20	32	11177	V <sub>GS</sub> = 4.5V, I <sub>D</sub> = 5A
Diode Forward Voltage	V <sub>SD</sub>	_	0.7	1.0	V	V <sub>GS</sub> = 0V, I <sub>S</sub> = 1.0A
DYNAMIC CHARACTERISTICS (Note 9)						
Input Capacitance	C <sub>iss</sub>	_	1060	_		V <sub>DS</sub> = 20V, V <sub>GS</sub> = 0V, f = 1.0MHz
Output Capacitance	Coss	_	84	_	pF	
Reverse Transfer Capacitance	Crss	_	58	_		
Gate Resistance	Rg	_	1.6	_	Ω	$V_{DS} = 0V$ , $V_{GS} = 0V$ , $f = 1.0MHz$
Total Gate Charge (V <sub>GS</sub> = 4.5V)	Qg	_	8.8	_		V <sub>DS</sub> = 20V, I <sub>D</sub> = 8A
Total Gate Charge (V <sub>GS</sub> = 10V)	Qg	_	19.1	_	nC	
Gate-Source Charge	Qgs	_	3.0	_	lic	
Gate-Drain Charge	$Q_{gd}$	_	2.5	_		
Turn-On Delay Time	t <sub>D(ON)</sub>	_	5.3	_		
Turn-On Rise Time	t <sub>R</sub>	_	7.1	_		$V_{DD} = 25V, R_L = 2.5\Omega$ $V_{GS} = 10V, R_g = 3\Omega$
Turn-Off Delay Time	t <sub>D(OFF)</sub>	_	15.1	_	ns	
Turn-Off Fall Time	t <sub>F</sub>	_	4.8	_		
Body Diode Reverse Recovery Time	t <sub>RR</sub>	_	10.5	_	ns	I <sub>F</sub> = 8A, di/dt = 100A/µs
Body Diode Reverse Recovery Charge	$Q_{RR}$	—	4.15	_	nC	I <sub>F</sub> = 8A, di/dt = 100A/μs

5. Device mounted on FR-4 PC board, with minimum recommended pad layout, single sided.

- Device mounted on FR-4 PC board, with minimum recommended pad layout, single sided.
  Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1inch square copper plate 7. I<sub>AS</sub> and E<sub>AS</sub> rating are based on low frequency and duty cycles to keep T<sub>J</sub> = +25°C.
  Short duration pulse test used to minimize self-heating effect.
  Guaranteed by design. Not subject to product testing.





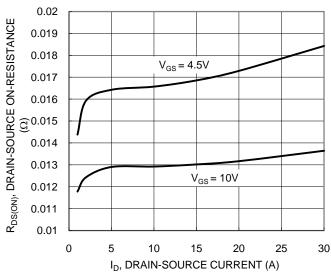


Figure 3. Typical On-Resistance vs. Drain Current and Gate Voltage

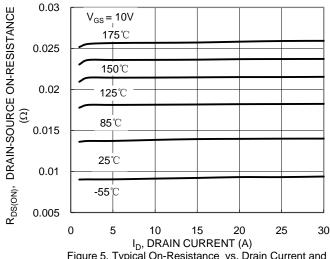
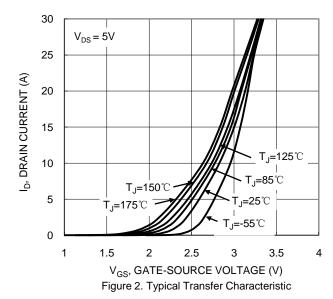
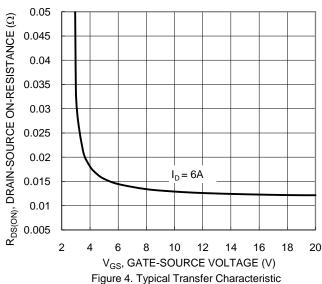


Figure 5. Typical On-Resistance vs. Drain Current and Temperature





RDS(ON), DRAIN-SOURCE ON-RESISTANCE 2.2 2 1.8  $V_{GS} = 10V, I_{D} = 6A$ (NORMALIZED) 1.6 1.4 1.2  $V_{GS} = 4.5V, I_{D} = 5A$ 1 8.0 0.6 0.4 50 75 100 125 150 175 T<sub>.J</sub>, JUNCTION TEMPERATURE (°C)

Figure 6.On-Resistance Variation with Temperature



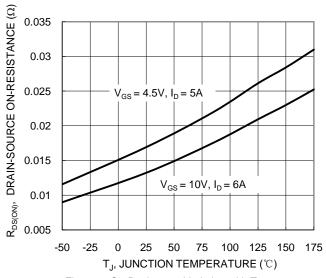
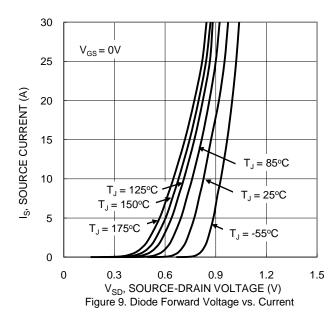
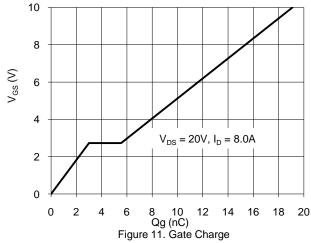
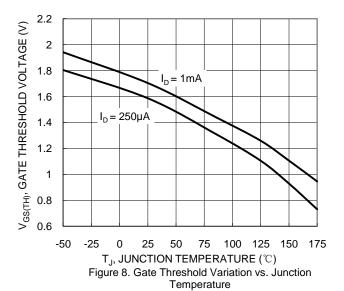
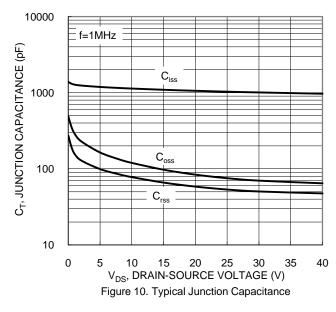


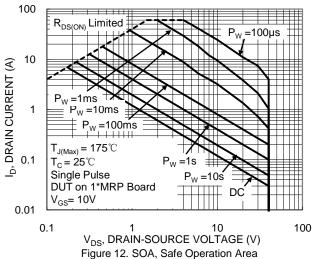
Figure 7. On-Resistance Variation with Temperature



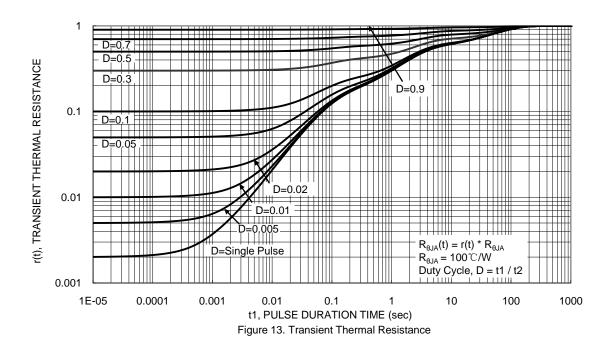










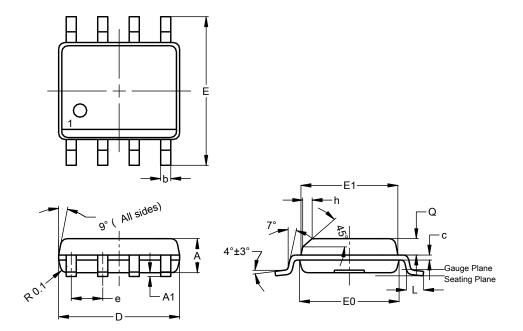




# **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

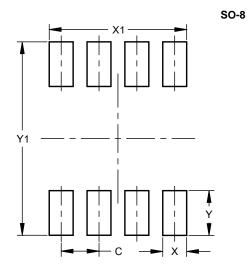
**SO-8** 



SO-8					
Dim	Dim Min Max				
Α	1.40	1.50	1.45		
A1	0.10	0.20	0.15		
b	0.30	0.50	0.40		
С	0.15	0.25	0.20		
D	4.85	4.95	4.90		
Е	5.90	6.10	6.00		
E1	3.80	3.90	3.85		
E0	3.85	3.95	3.90		
е			1.27		
h	-		0.35		
L	0.62	0.82	0.72		
Q	0.60	0.70	0.65		
All Dimensions in mm					

# **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.



Dimensions	Value (in mm)			
С	1.27			
Х	0.802			
X1	4.612			
Y	1.505			
Y1	6.50			



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